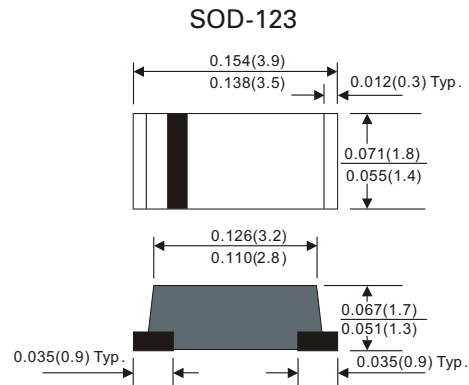
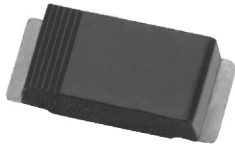


PSL12-M thru PSL14-M

SILICON EPITAXIAL PLANER TYPE

Low VF Chip Schottky Diodes



Dimensions in inches and (millimeters)

FEATURES

- Plastic package has Underwriters Laboratory
- Flammability Classification 94V-0 Ufizing Flame
- Retardant Epoxy Molding Compound.
- For surface mounted applications.
- Exceeds environmental standards of ML-S-19500/228
- Low leakage current

MECHANICAL DATA

Case : JEDEC SOD-123/MINI SMA molded plastic
 Terminals : Solder plated, solderable per
 MIL-STD-750, Method 2026
 Polarity : Indicated by cathode band
 Mounting Position : Any
 Weight : 0.04gram

MAXIMUM RATINGS (at $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	Min.	Typ.	Max.	UNITS
Forward rectified current	See Fig.2	I_o			1.0	A
Forward surge current	8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}			30	A
Reverse current	$V_R=V_{RRM}$ $T_A=25^\circ\text{C}$	I_R			1.0	mA
	$V_R=V_{RRM}$ $T_A=100^\circ\text{C}$				10	mA
Thermal resistance	Junction to ambient	R_{JA}		42		$^\circ\text{C} / \text{W}$
Diode junction capacitance	$F=1\text{MHz}$ and applied 4vDC reverse voltage	C_J		130		pF
Storage temperature		T_{STG}	-55		+150	$^\circ\text{C}$

SYMBOLS	MARKING CODE	V_{RRM}^{*1} (V)	V_{RMS}^{*2} (V)	V_R^{*3} (V)	V_F^{*4} (V)	Operating Temperature ($^\circ\text{C}$)
PSL12-M	L2	20	14	20	0.38	-55 to + 125
PSL13-M	L3	30	21	30	0.40	
PSL14-M	L4	40	28	40	0.40	

*1 Repetitive peak reverse peak reverse

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage

PSL12-M thru PSL14-M

SILICON EPITAXIAL PLANER TYPE

RATING AND CHARACTERISTICS CURVES PSL12-M THRU PSL14-M

FIG.1-TYPICAL FORWARD CHARACTERISTICS

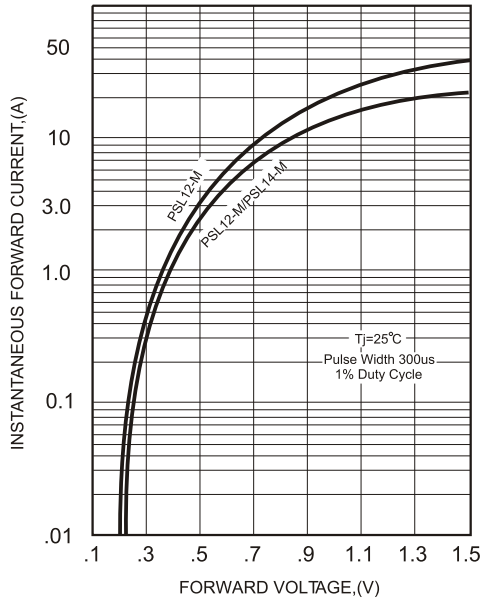


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

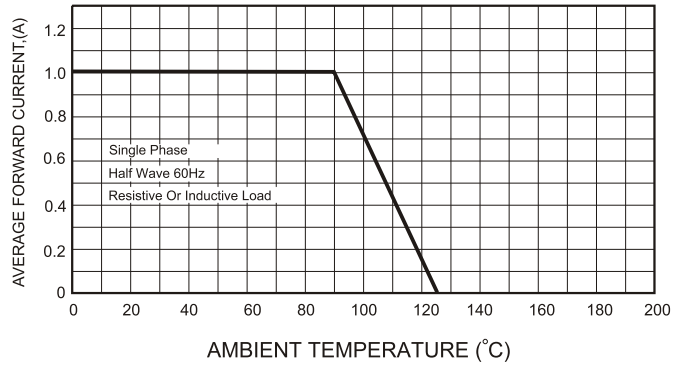


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

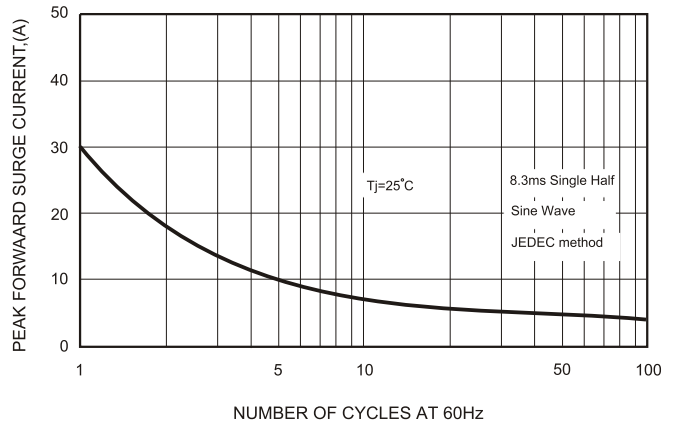


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

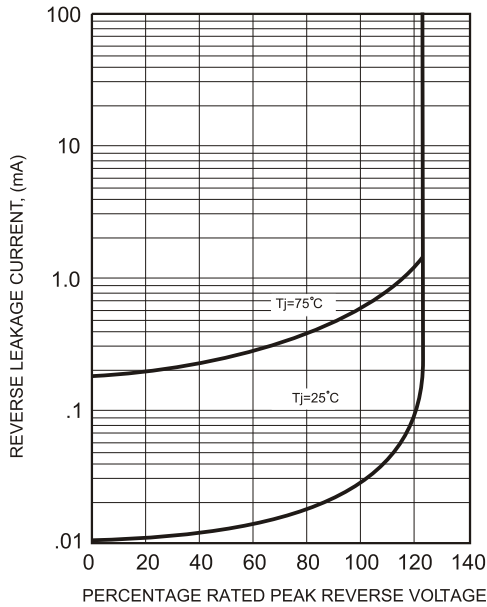


FIG.5-TYPICAL JUNCTION CAPACITANCE

